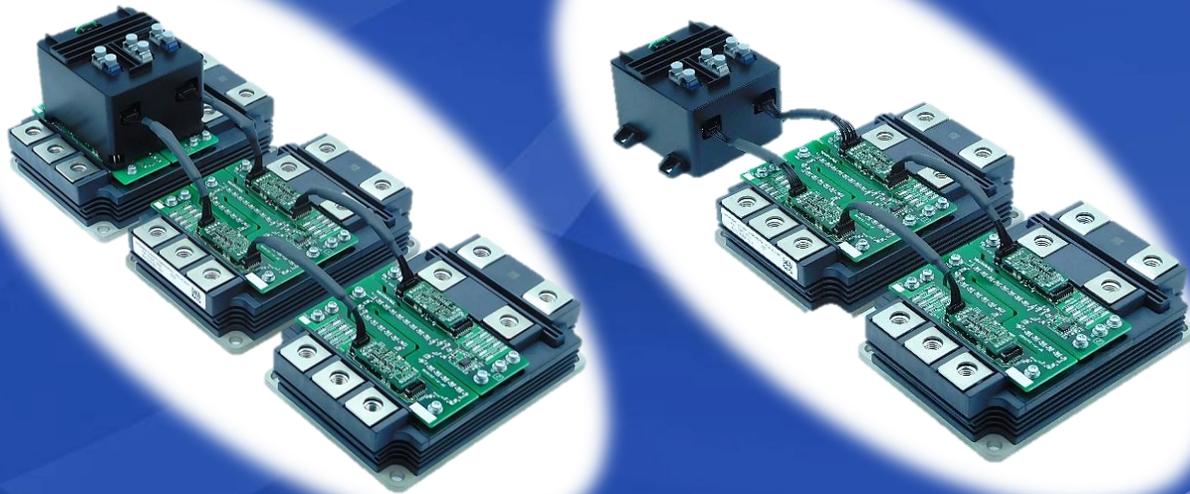


**Gate Driver** optimized for Mitsubishi Electric 3300V

**Full SiC** power module **FMF750DC-66A / FMF800DC-66BEW**



SUSTAINABLE  
DEVELOPMENT  
**GOALS**

**TAMURA**

Your One and Only Company

# Index

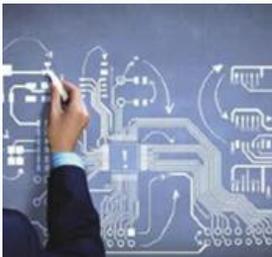
- 01 When, Why, we started development gate drivers
- 02 Tamura Total solution for Traction Market
- 03 Three features of Tamura Gate Driver
  - Scalability
  - Parallel drive
  - Low coupling capacitance
- 04 Introduction of Tamura Gate driver 2LH / 2XH series
- 05 Products line-up
- 06 Matching data (2-pulse / Short circuit)  
(Data is from Mitsubishi Electric  
FMF750DC-66A and FMF800DC-66BEW)

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 01 Why, we started development gate drivers



**Transformer Technology**



**Circuit design Technology**



**Potting Technology**



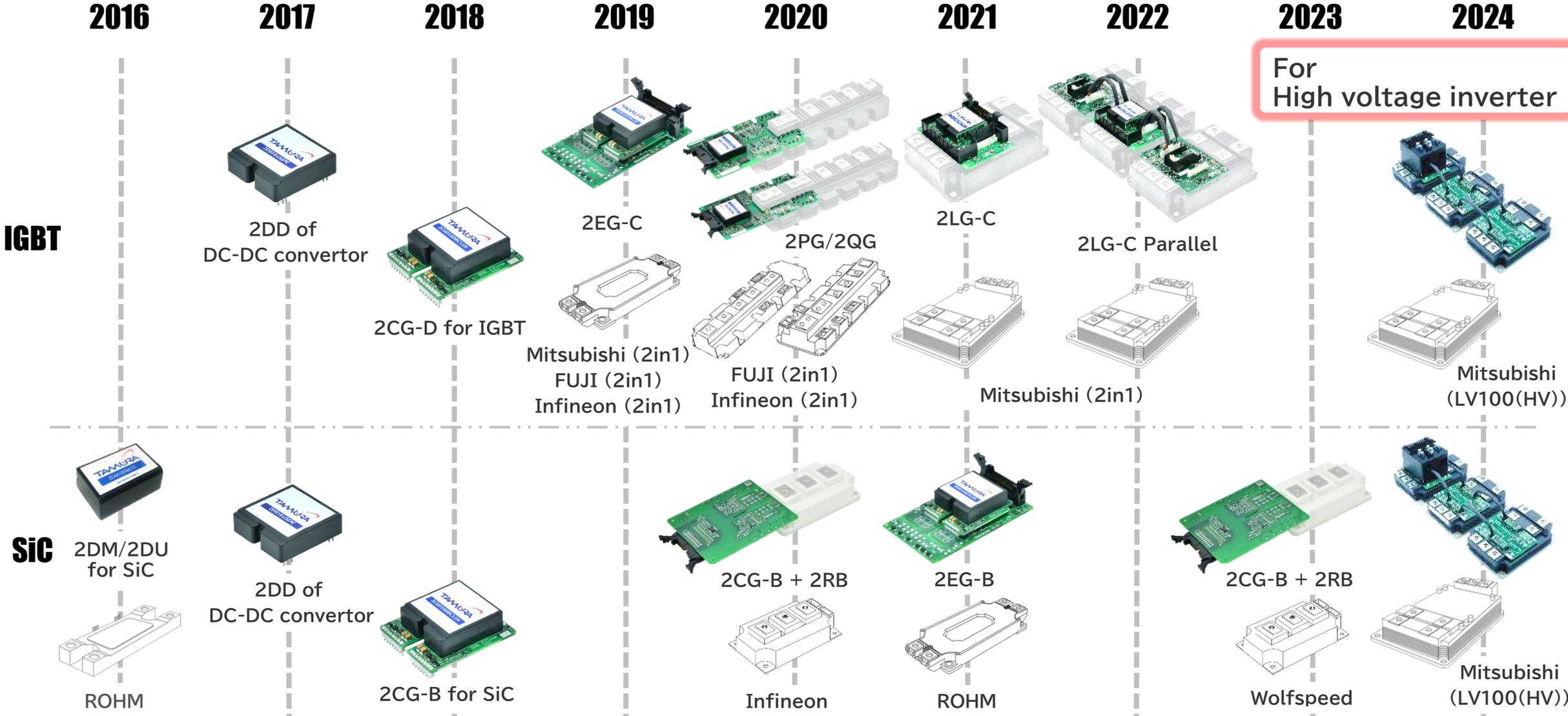
**EMI/EMC Solution**



**Market Awareness**

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

01 When, we started development gate drivers



# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 02 Tamura Total solution for Traction Market

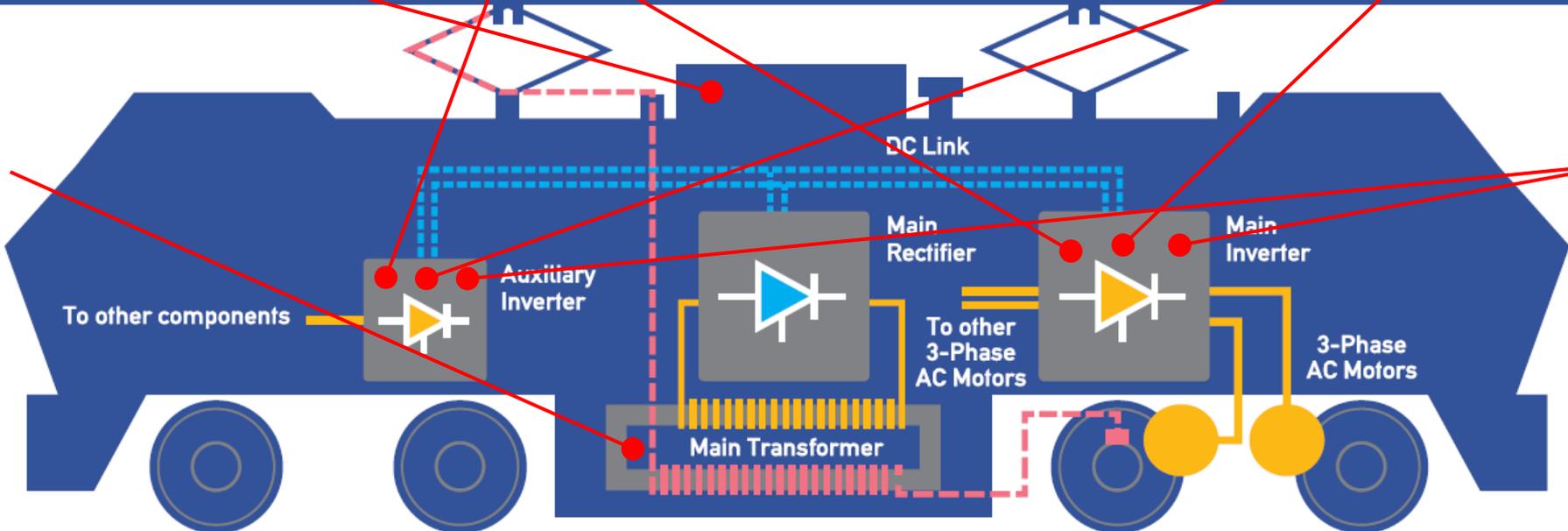
Collaboration of Power semiconductors manufacturers



Roof mounted



Underframe mounted



**Provide of main components for Traction converter!**

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 02 Tamura Total solution for Traction Market

Underframe mounted



Reactor

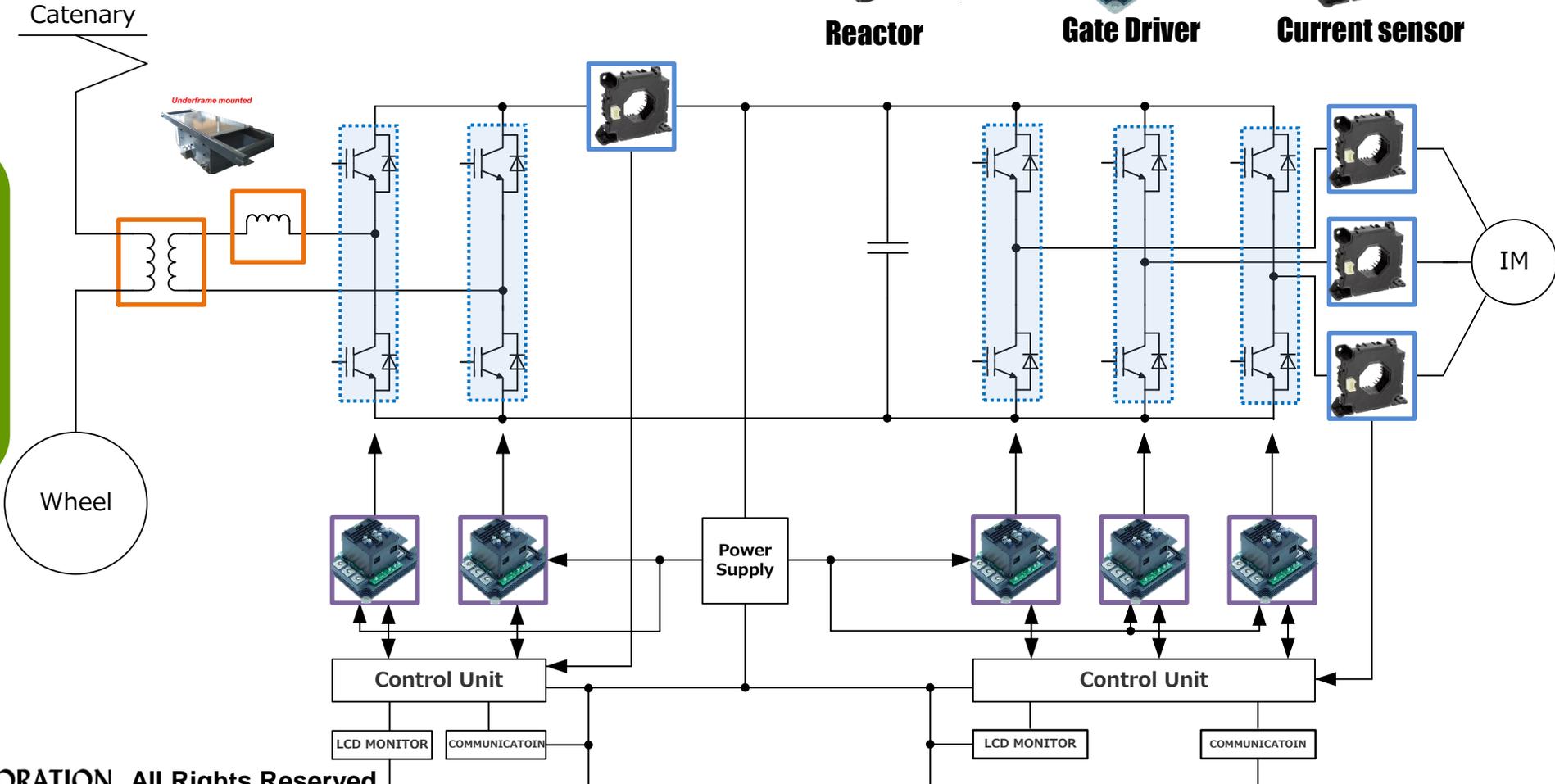


Gate Driver

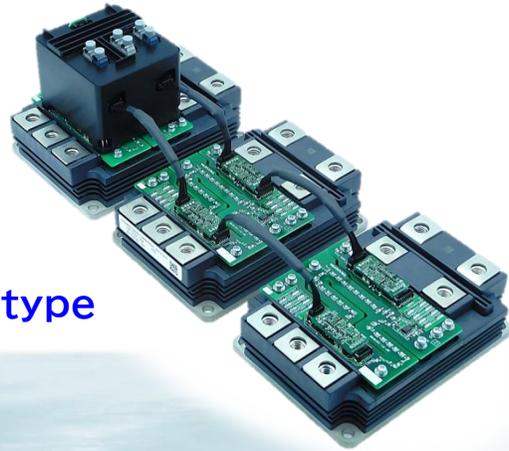


Current sensor

### Traction inverter



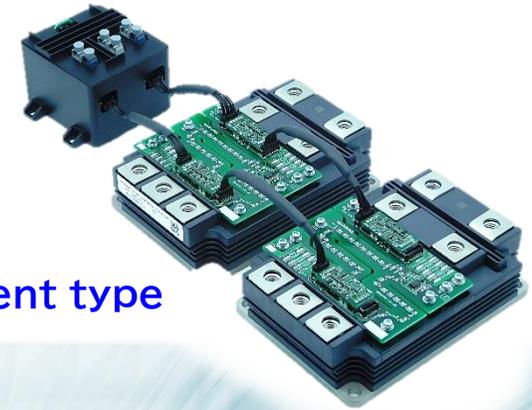
# *Suitable for Traction Converter*



Top mounting type



▶ Check here !

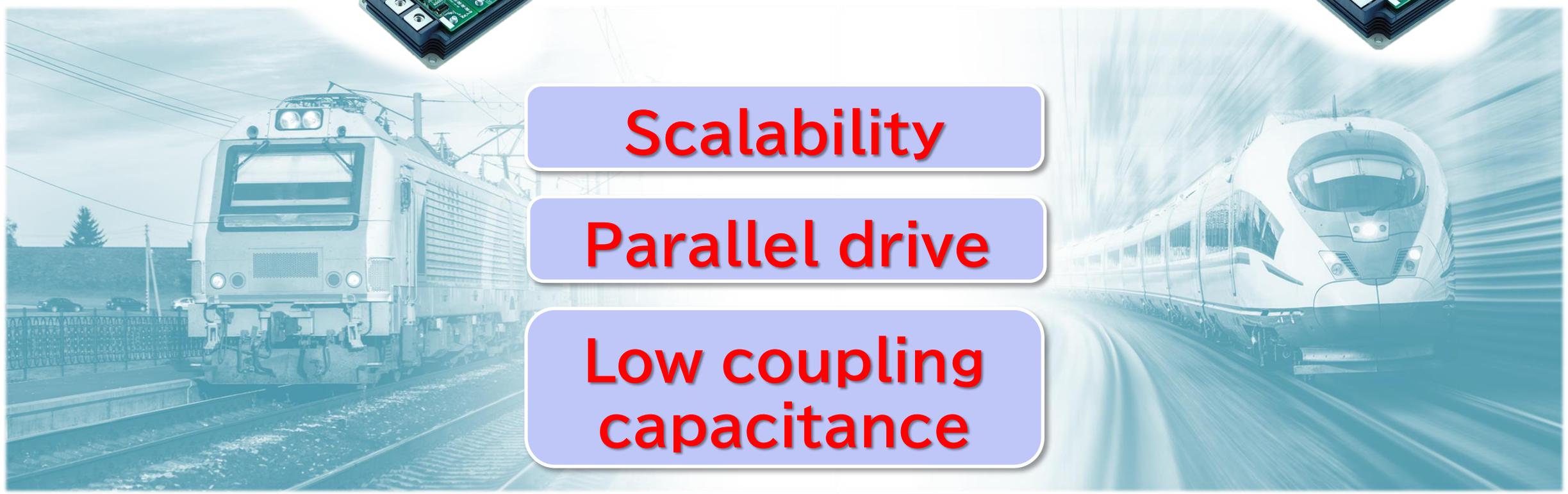


Side placement type

**Scalability**

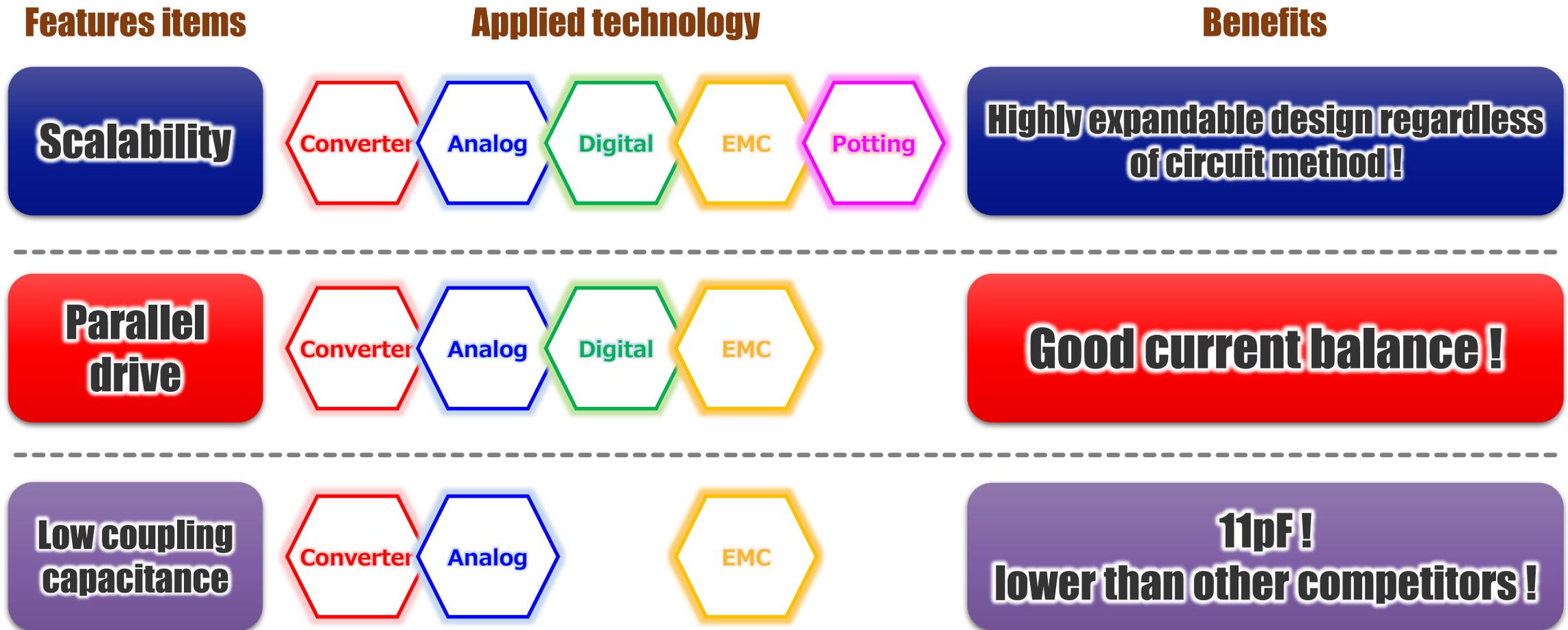
**Parallel drive**

**Low coupling capacitance**



# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 03 Three features of Tamura Gate Driver



# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 03 Three features of Tamura Gate Driver

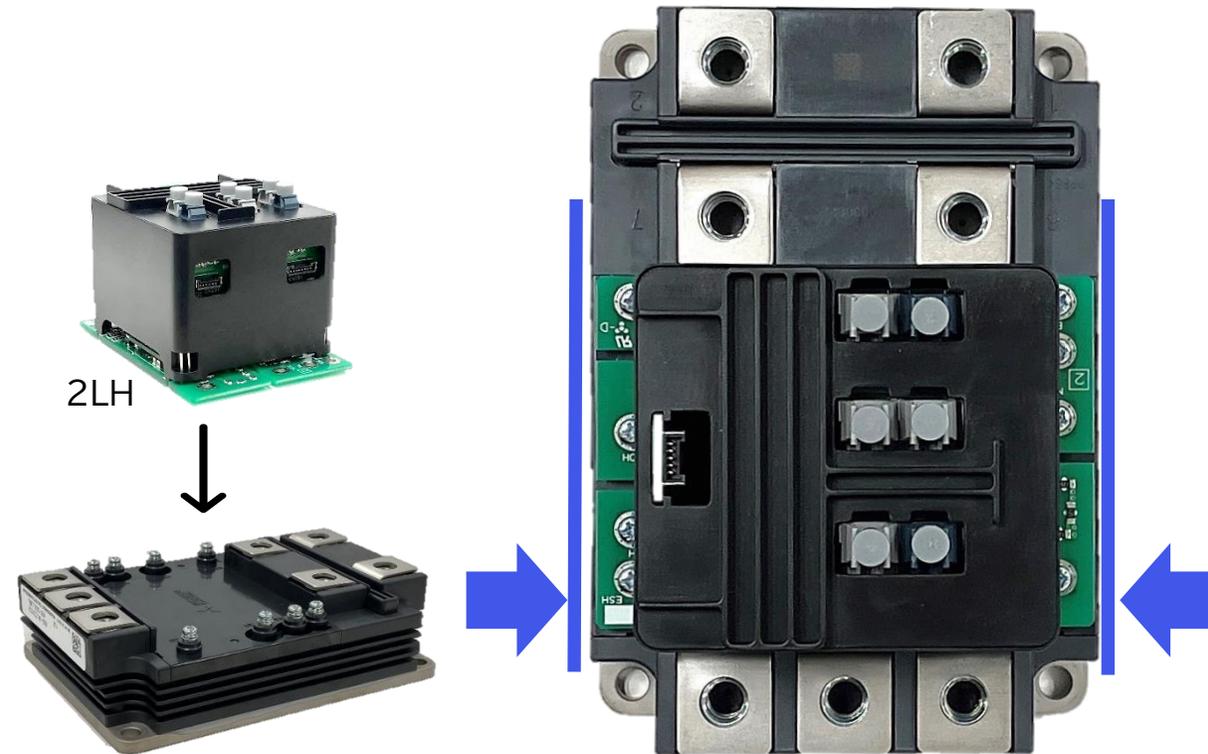
**Scalability**

**Compact size!**  
**Less than 50%\***

**322cc**

\* Compared to other companies

**Can be mounted on Power module!**



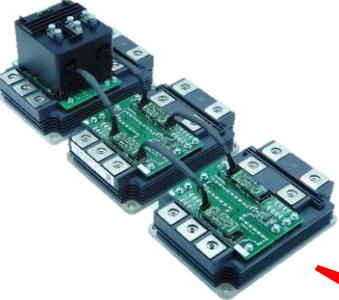
**Same width as power module**

**Contribute to compact design of system thanks to "no protrusion"**

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

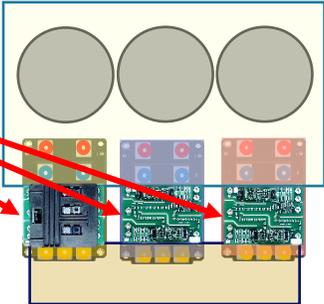
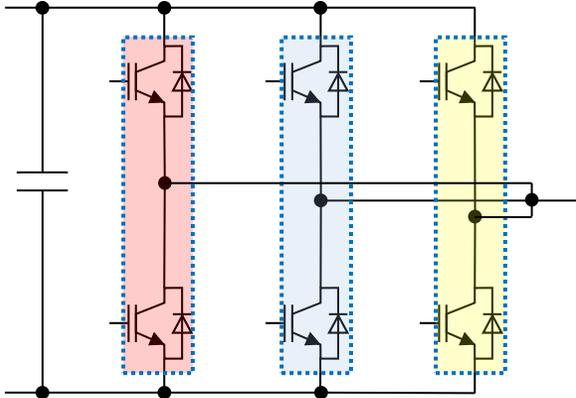
## 03 Three features of Tamura Gate Driver

**Scalability**

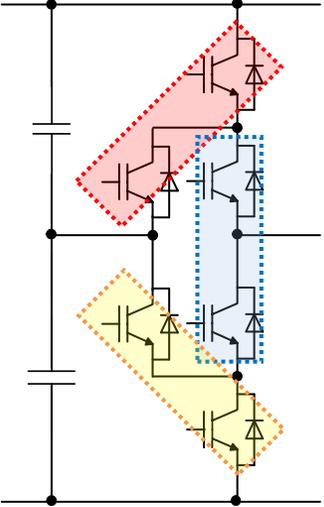


2LH + Follower

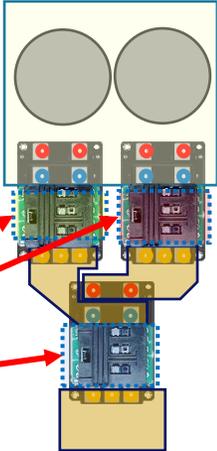
FMF750DC-66A  
With 2-level / 3pcs paralleling



FMF750DC-66A  
With 3-level ANPC (I-Type)



2LH



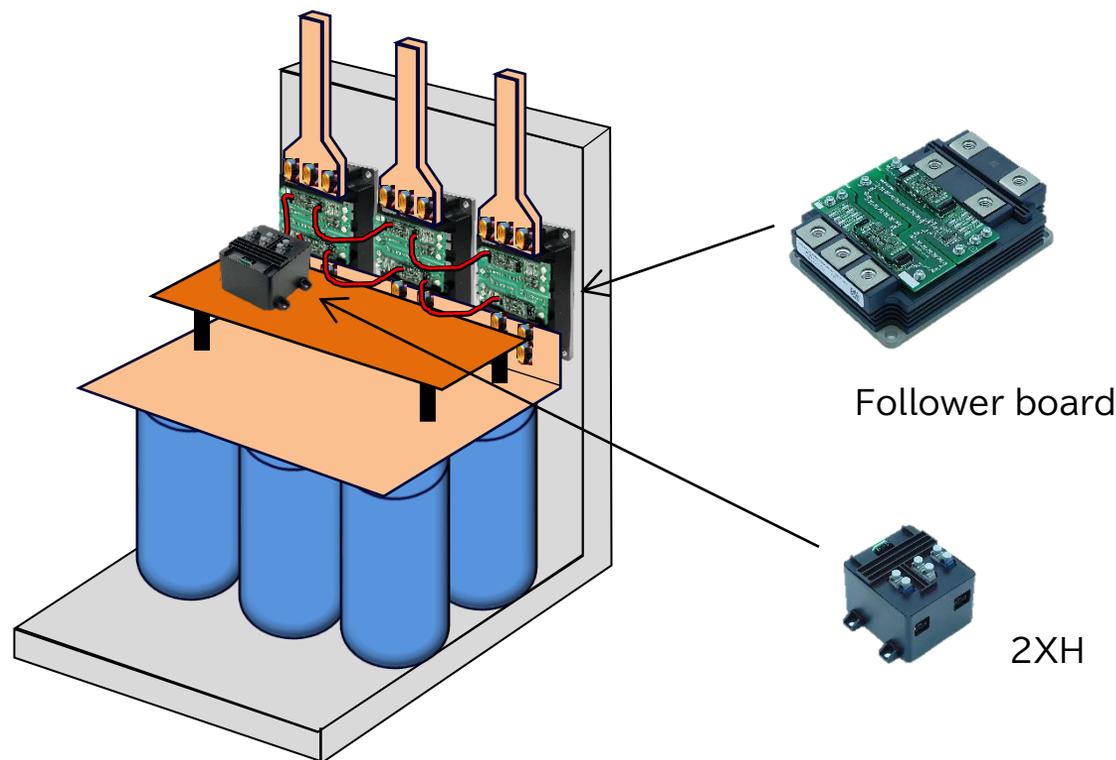
**Highly expandable design regardless of circuit method**

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 03 Three features of Tamura Gate Driver

### Overhead space available !

Example) Power electronic building block (PEBB)

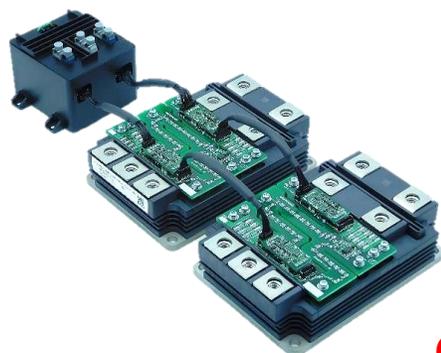


**Scalability**

**Compact size!**  
Less than 50% \*

**322cc**

\* Compared to other companies



**Contribute to compact design of system thanks to "no protrusion"**

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 03 Three features of Tamura Gate Driver

**Parallel drive**



**Coming soon !**

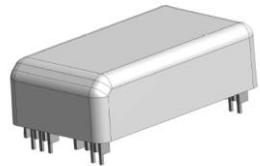
Event	2024		2025	
ES2 for FMF800DC-66BEW	Design review			
	Evaluation (Short circuit)			
	Evaluation (3parallel, ~Oct/ '24)			
			★ MP Start	

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

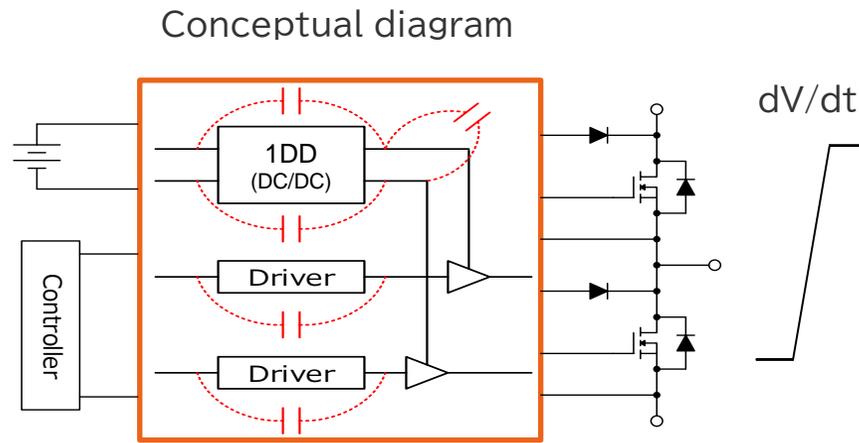
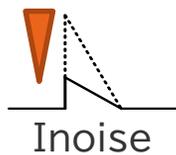
## 03 Three features of Tamura Gate Driver

**Low coupling capacitance**

No malfunctions even during high-speed switching.  
 ⇒ **Reduction of parasitic capacitance !**

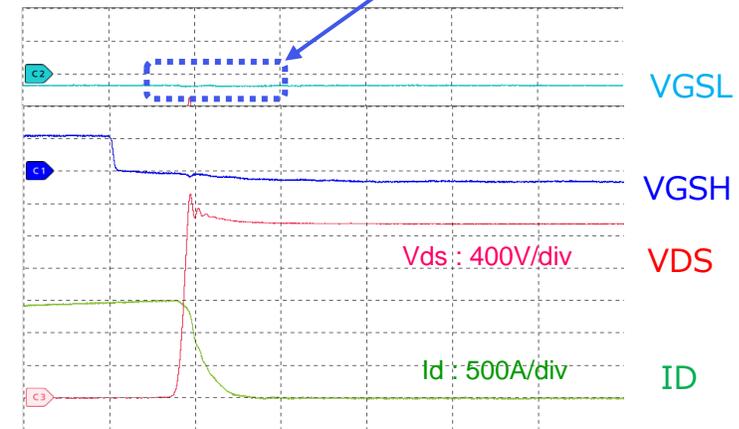


No malfunction at high dV/dt



$$\text{Inoise} = C_{\text{stray}} \times \frac{dV}{dt}$$

FMF750DC-66A **No malfunctions !**



**dV/dt = 19.8kV/us**

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 04 Introduction of Tamura Gate driver 2LH / 2XH series

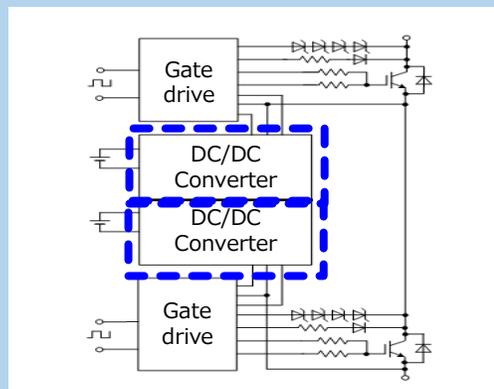
**Product**

**DC/DC Converter**

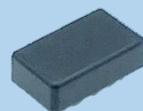
**Function**

**PM designated  
DC/DC Converter**

**Block diagram**



**Appearance**

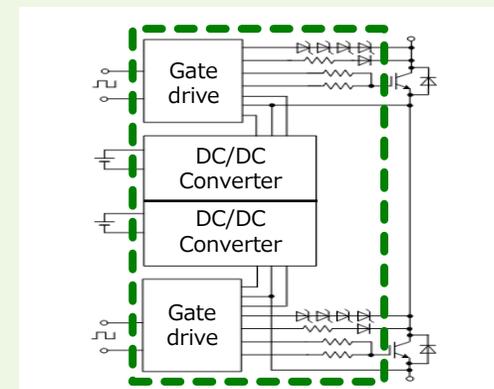


1DD

**Gate Driver Unit  
DC/DC Converter**

**+ Gate drive Circuit**

**+ Gate resistors Protective function**



2LH

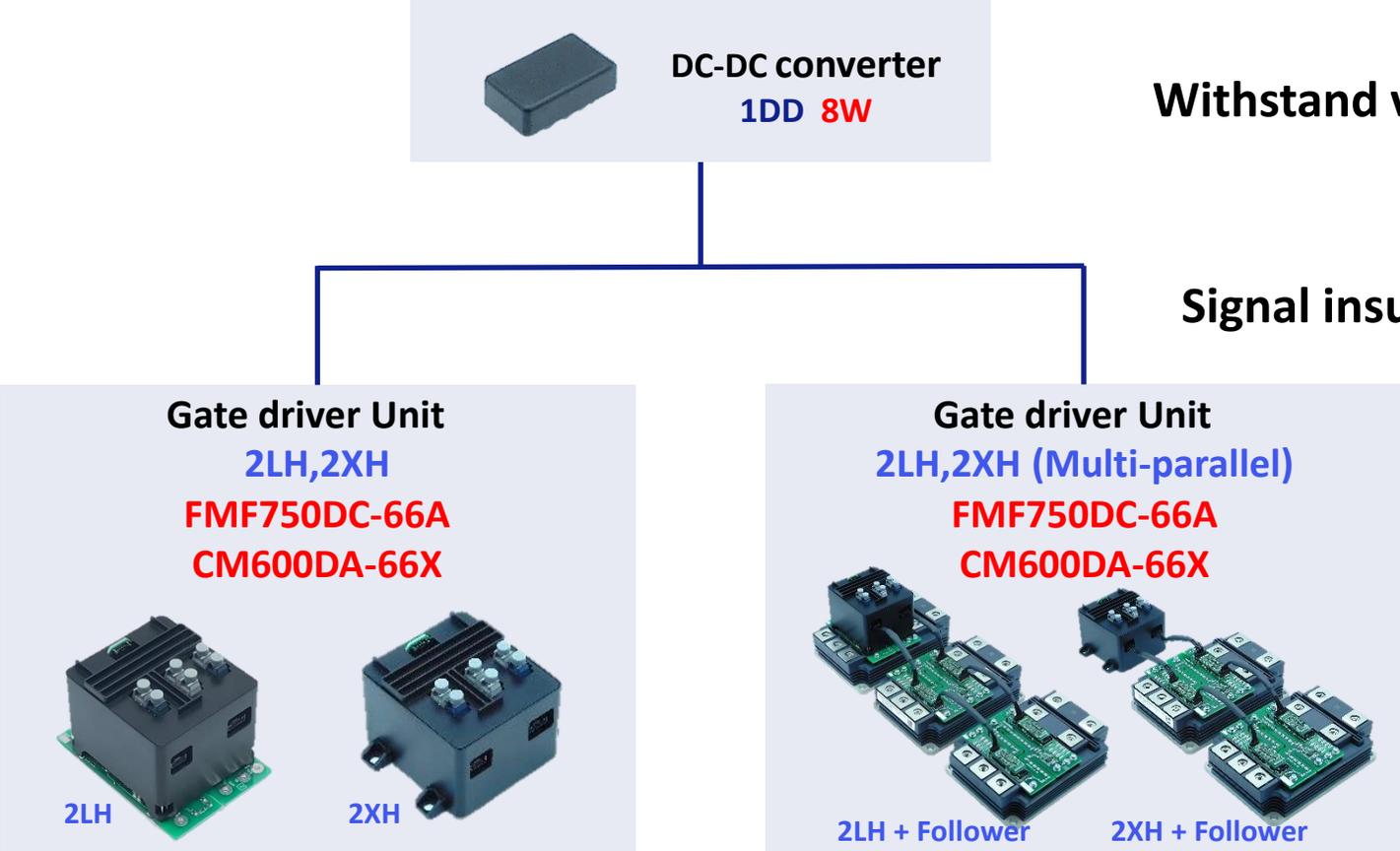


2XH

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 04 Introduction of Tamura Gate driver 2LH / 2XH series

### Products tree



Withstand voltage : **10.8kV**

Signal insulation : **Optical**

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 04 Introduction of Tamura Gate driver 2LH / 2XH series

### Specification

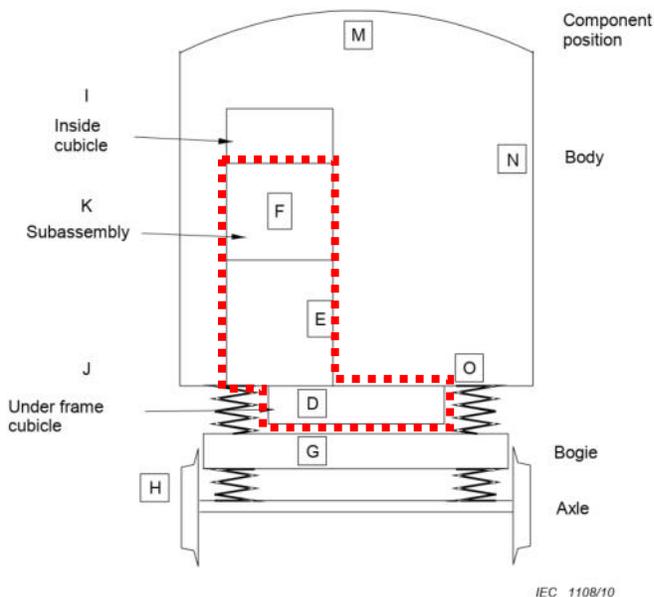


Item	Specification	Actual
Isolation voltage (Pri-Sec)	10.8kV	>18kV
Isolation voltage (Sec-Sec)	6.7kV	Checking limit value
Partial discharge extinction voltage	4.95kVpeak(min)	Checking limit value
Clearance/Creepage(Pri-Sec)	23.8mm/50.4mm	←
Clearance/Creepage(Pri-Sec)	8mm/22mm	←
Coupling capacitance	11pF	←
Signal interface	Fiber-optic	←
Size	70.2X76.3X60.2=322cc	←

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 04 Introduction of Tamura Gate driver 2LH / 2XH series

### Specification ( Vibration tests )



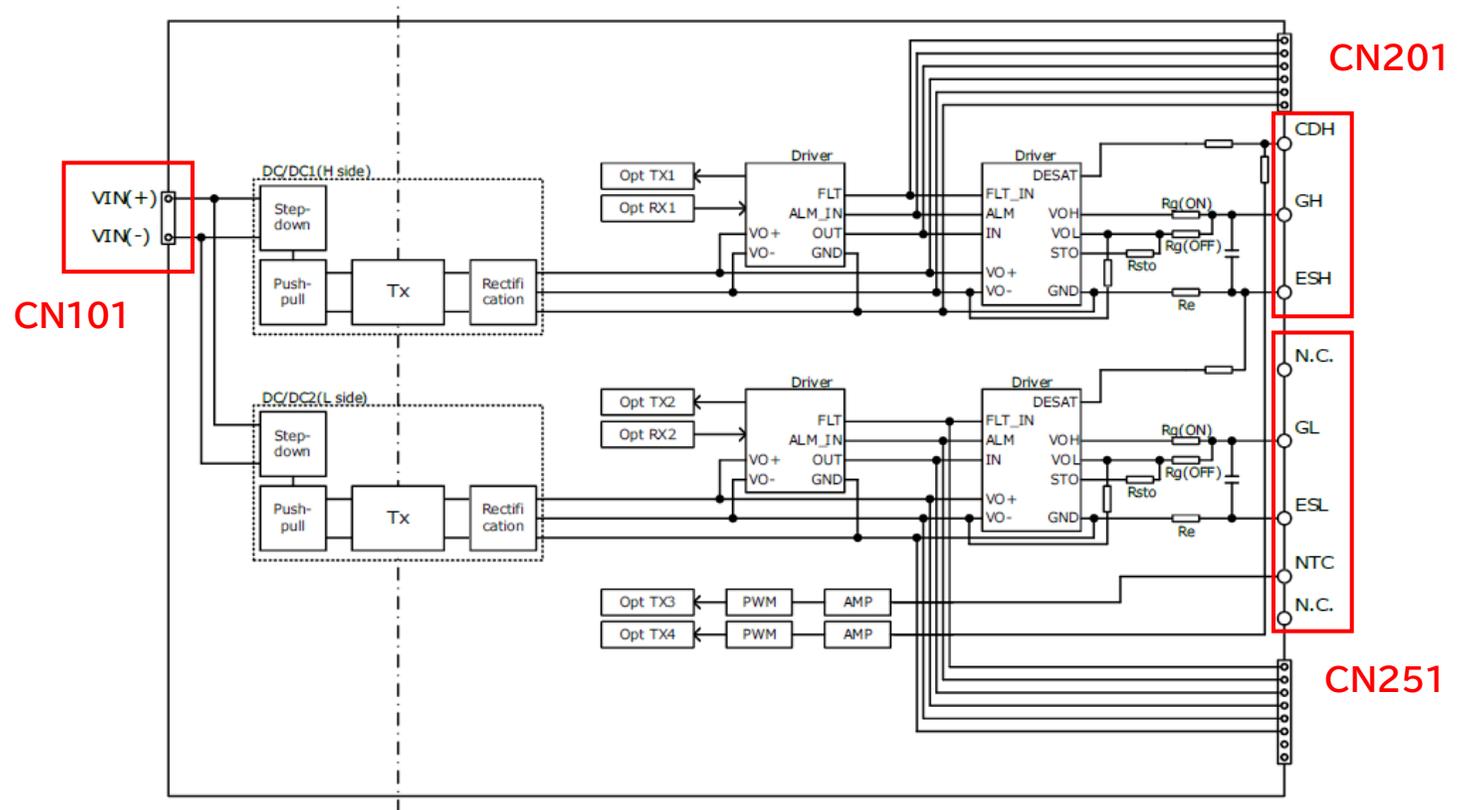
Category	Location	Description of equipment location
1 Class A	M N O I and J	Components which are mounted directly on to or under the car body
1 Class B	D	Components mounted into an underframe cubicle which is in turn fixed to the car body
1 Class B	K and E	Components mounted into a large internal cubicle which is in turn fixed to the car body
1 Class B	F	Components mounted into subassemblies which are in turn mounted into a cubicle which is in turn fixed to the car body
2	G	Cubicles, subassemblies, equipment and components which are mounted on the bogie of a railway vehicle
3	H	Subassemblies, equipment and components or assemblies which are mounted on to the axle assembly of a railway vehicle

Category	Location	Vibration waveform	Amplitude frequency	Maximum acceleration (Reference)	Test time	Standard
1-ClassB	D,K,E,F	Random	12.6mm 2~150Hz	16.89m/s <sup>2</sup>	XYZ Each 5h	IEC61373

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 04 Introduction of Tamura Gate driver 2LH / 2XH series

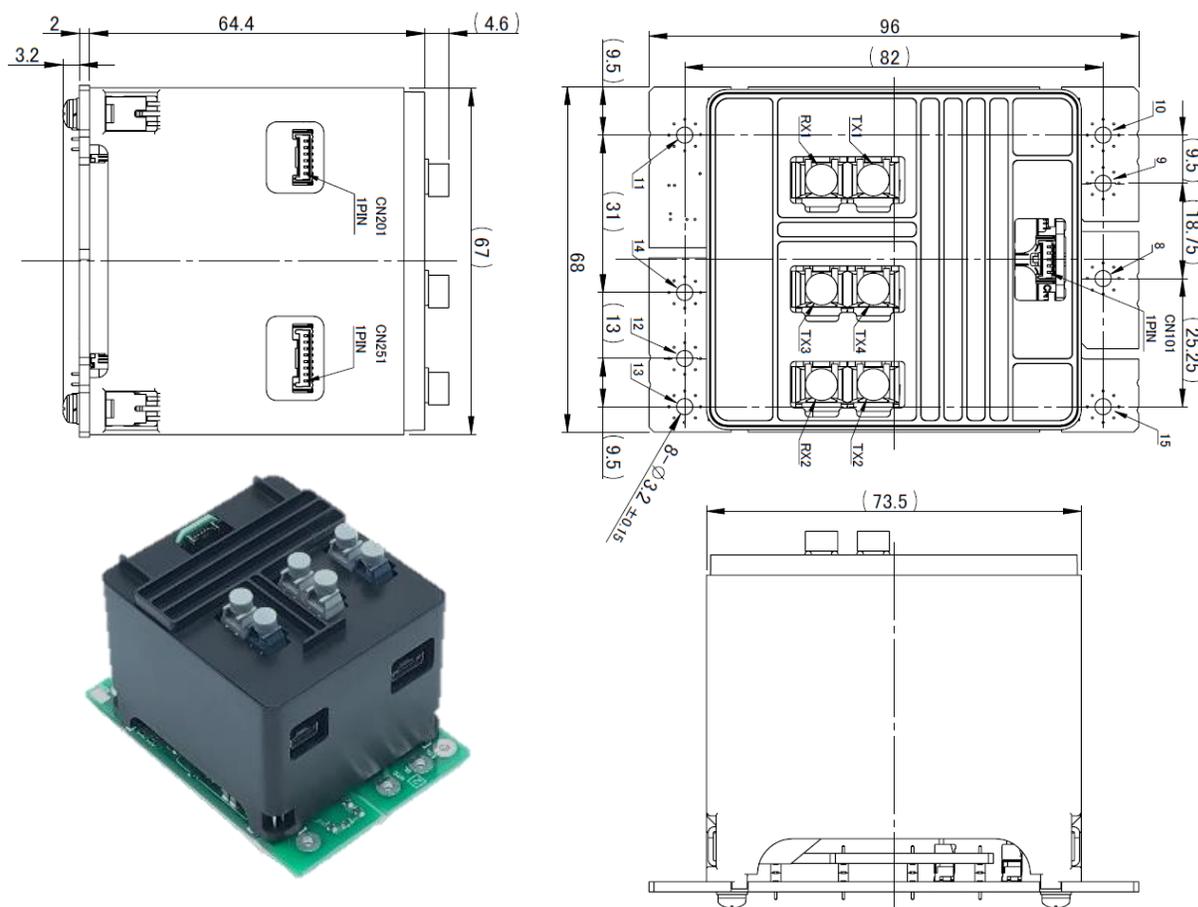
### Block diagram



# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 04 Introduction of Tamura Gate driver 2LH / 2XH series

### Out line & Pin function



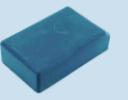
Pin No.	Channel	Function
CN101	Common	DC/DC input
RX1	Upper arm	Input signal (Receiver)
TX1	Upper arm	Alarm signal (Transmitter)
RX2	Lower arm	Input signal (Receiver)
TX2	Lower arm	Alarm signal (Transmitter)
TX3	Lower arm	PWM output of measured NTC temperature (Transmitter)
TX4	Lower arm	PWM output of measured DC link voltage (Transmitter)
CN201	Upper arm	For parallel connection
CN251	Lower arm	For parallel connection

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module



## 06 Products line-up

Underdevelopment

Package	I <sub>C</sub> /I <sub>D</sub>	Part No	Gate Driver Unit			DC-DC converter						
			2LH / 2XH			1DD						
	V <sub>ce</sub> = 1700V											
	1200	CM1200DA-34X	 2LH	 2XH	 Follower	+15/-10V type	 +15/-10V type					
	V <sub>ds</sub> or V <sub>ce</sub> = 3300V											
	375	FMF375DC-66A	 2LH			 2XH		 Follower				
	750	FMF750DC-66A								+17V/-5V type		+17V/-5V type
FMF750DC-66A-1												
800	FMF800DC-66BEW	+17V/-7V type								+17V/-7V type		
600	CM600DA-66X	+15/-10V type		+15/-10V type								

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 06 Matching data (2-pulse / Short circuit)

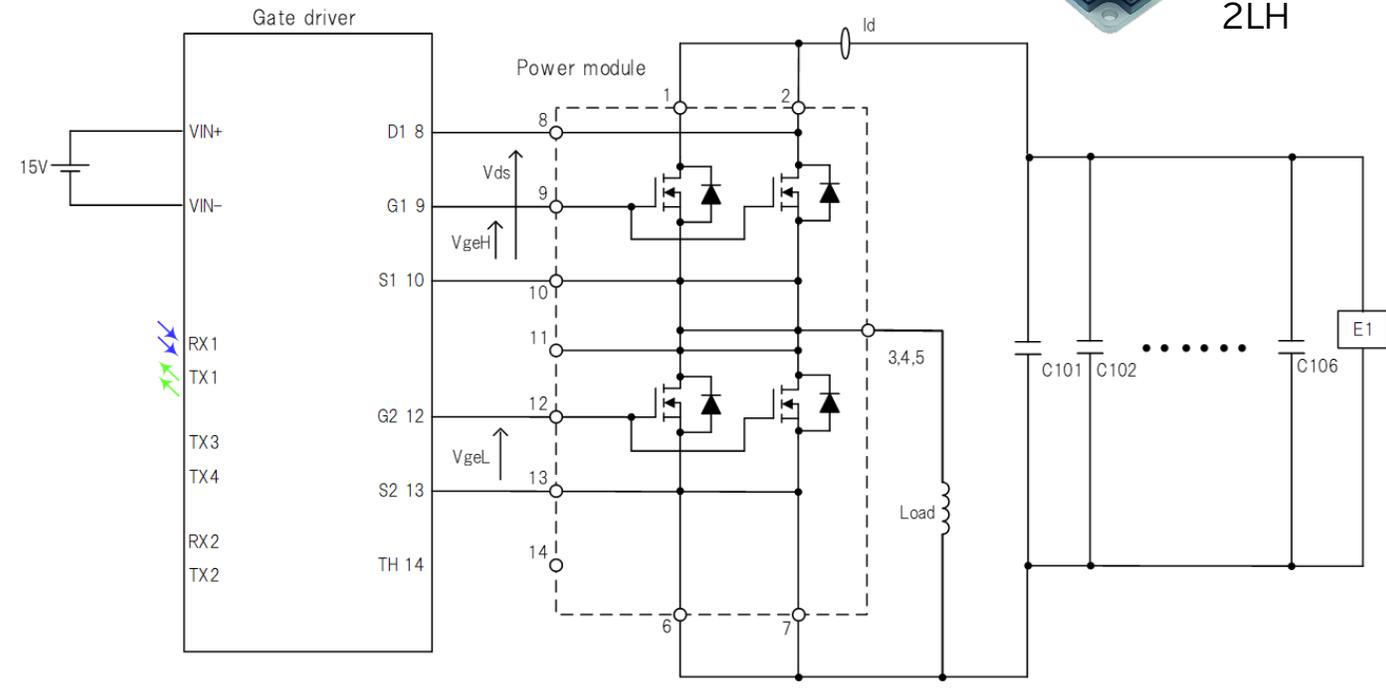
(Data is from Mitsubishi Electric FMF750DC-66A)



### Test condition

Item	Description
Device	FMF750DC-66A
Gate driver	2LH series (TBD)
Gate voltage	+17V/-5V
Gate resistor	Ron:2.0Ω, Roff:0.9Ω
DC-link voltage (VCC)	1800V, 2200V
Main circuit current	750A, 1500A
Switching condition	Period:100us on duty:20-30%
Load inductance	55uH
Junction temperature	150°C

### Test Circuit for Upper arm



C101-106 : 490uF  
Ls :About 40nH

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 06 Matching data (2-pulse / Short circuit)

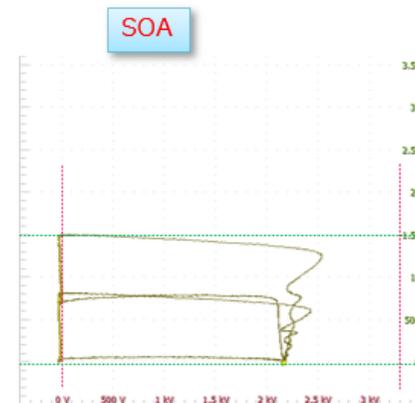
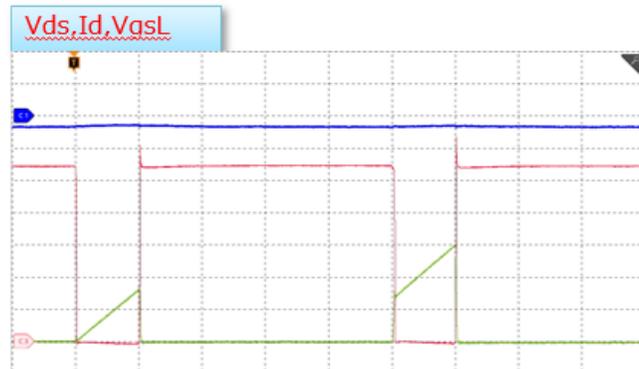
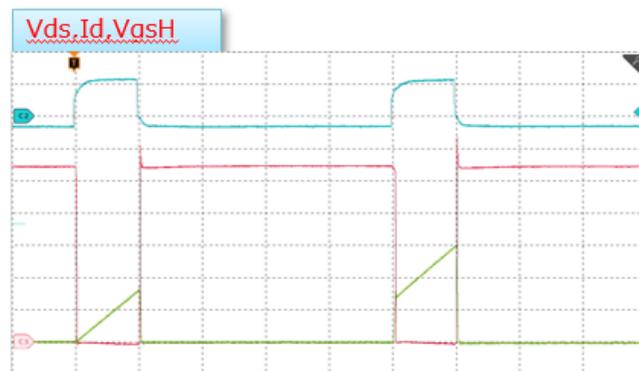
(Data is from Mitsubishi Electric FMF750DC-66A)

### 2 pulse test of upper arm

VCC=2200V, Ron:2.0Ω, Roff:0.9Ω, Tj=150°C

VgsL:15V/div, VgsH:15V/div, Vds:400V/div, Id:500A/div, t:20us/div

[2 pulse test]



2LH

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 06 Matching data (2-pulse / Short circuit)

(Data is from Mitsubishi Electric FMF750DC-66A)

### 2 pulse test of upper arm (expansion)

VCC=2200V, Ron:2.0Ω, Roff:0.9Ω, Tj=150°C

VgsL:15V/div, VgsH:15V/div, Vds:400V/div, Id:500A/div, t:1us/div



2LH

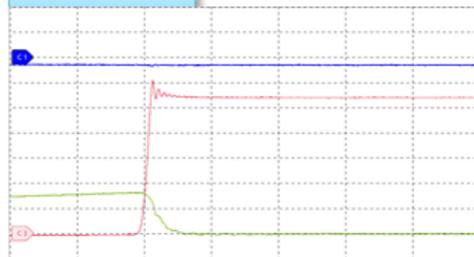
Turn OFF / Id =750A

Vds, Id, VgsH



Id  
750A

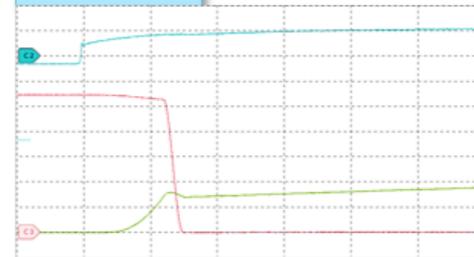
Vds, Id, VgsL



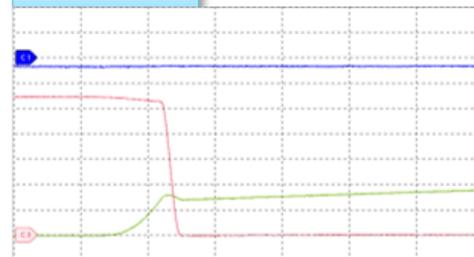
Item	Measurement Value	unit
Vdsp	2428	V
dV/dt	17.3	kV/us
dI/dt	4.7	kA/us
Eoff	358	mJ

Turn ON / Id =750A

Vds, Id, VgsH



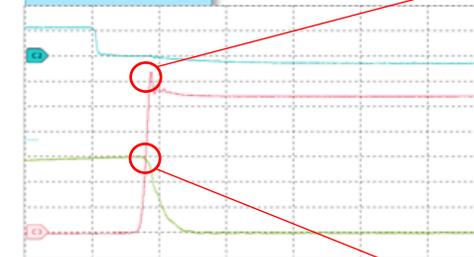
Vds, Id, VgsL



Item	Measurement Value	unit
dV/dt	11.1	kV/us
dI/dt	1.8	kA/us
Eon	629	mJ

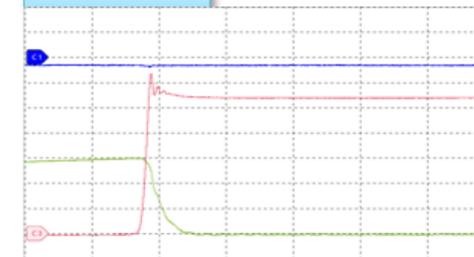
Turn OFF / Id =1500A

Vds, Id, VgsH



Vds = 2541V

Vds, Id, VgsL



Id  
1500A

Item	Measurement Value	unit
Vdsp	2541	V
dV/dt	19.8	kV/us
dI/dt	5.4	kA/us
Eoff	795	mJ

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

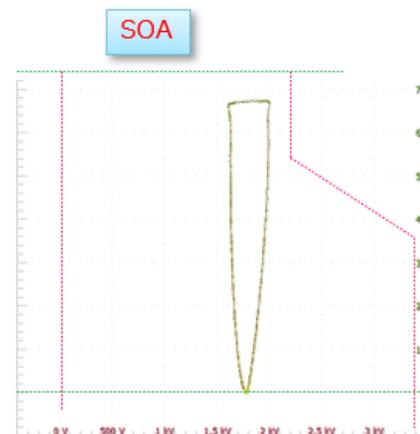
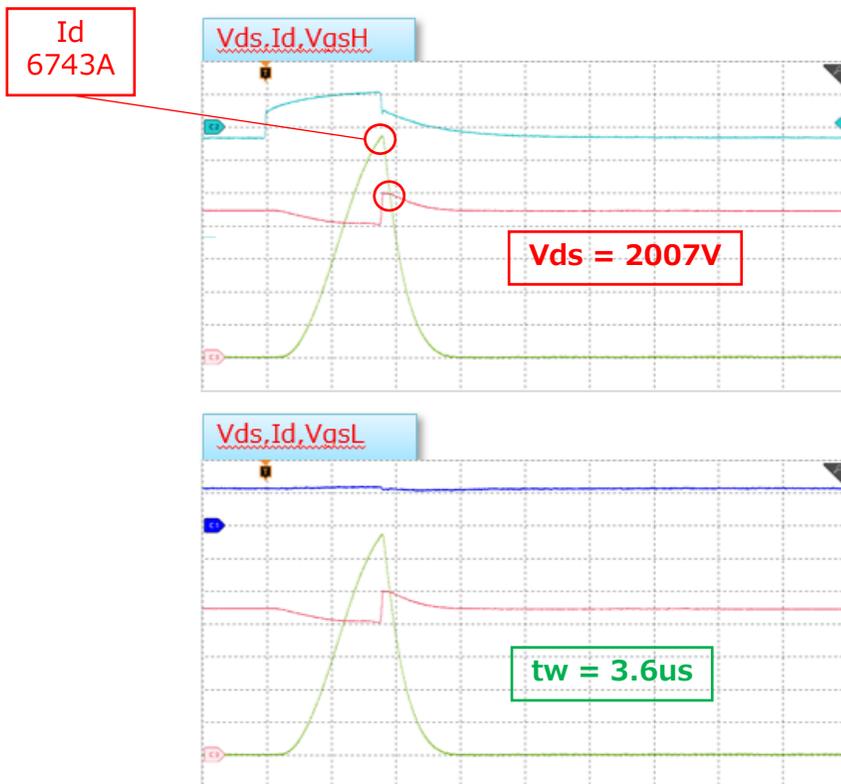
## 06 Matching data (2-pulse / Short circuit)

(Data is from Mitsubishi Electric FMF750DC-66A)

### Short circuit test of upper arm

VCC=1800V, Ron:2.0Ω, Roff:0.9Ω, Tj=150°C

VgsL:15V/div, VgsH:15V/div, Vds:400V/div, Id:1kA/div, t:2us/div



Item	Measurement Value	unit
Vdsp	2007	V
Idp	6743	A
tsc	3.6	us

※tsc : 10% to 90% of Vgs

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 06 Matching data (2-pulse / Short circuit)

(Data is from Mitsubishi Electric FMF800DC-66BEW)

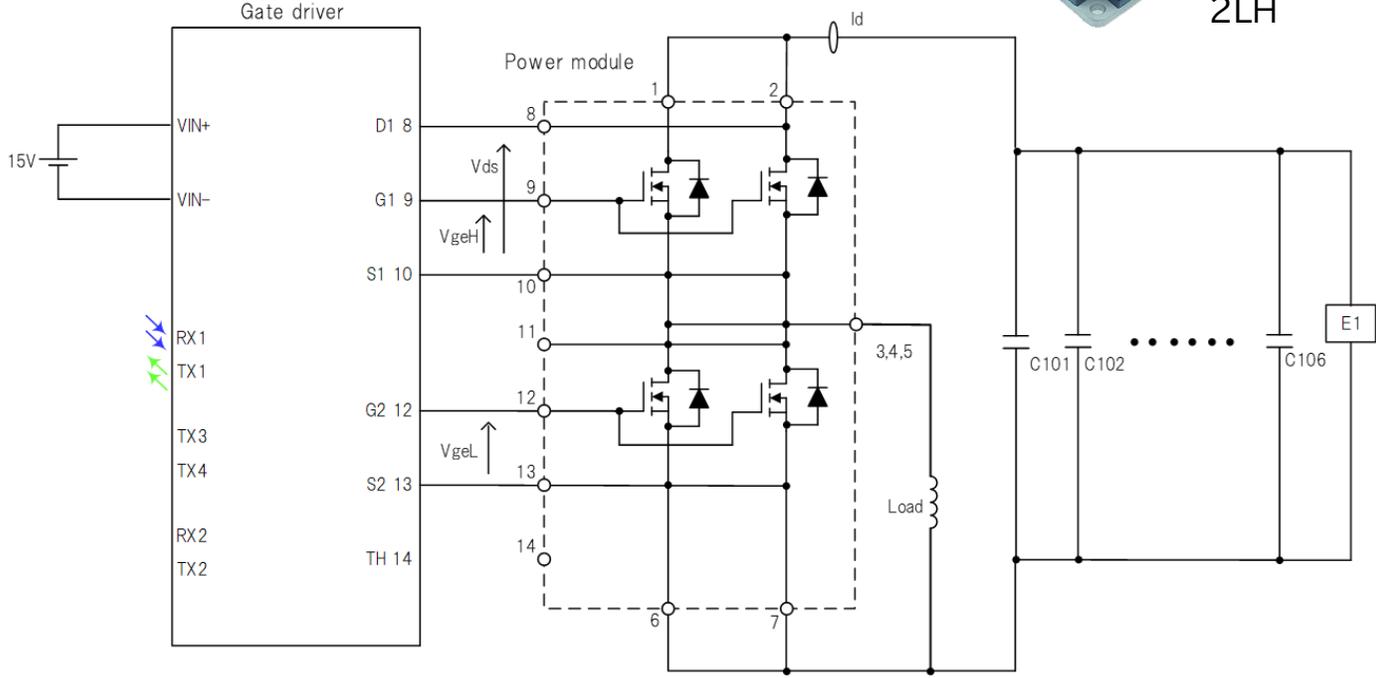


2LH

### Test condition

Item	Description
Device	FMF800DC-66BEW
Gate driver	2LH series (TBD)
Gate voltage	+17V/-7V
Gate resistor	Ron:1.5Ω, Roff:1.5Ω
DC-link voltage (VCC)	2200V
Main circuit current	800A, 1600A
Switching condition	Period:100us on duty:20-30%
Load inductance	55uH
Junction temperature	150°C

### Test Circuit for Upper arm



C101-106 : 490uF  
Ls :About 40nH

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 06 Matching data (2-pulse / Short circuit)

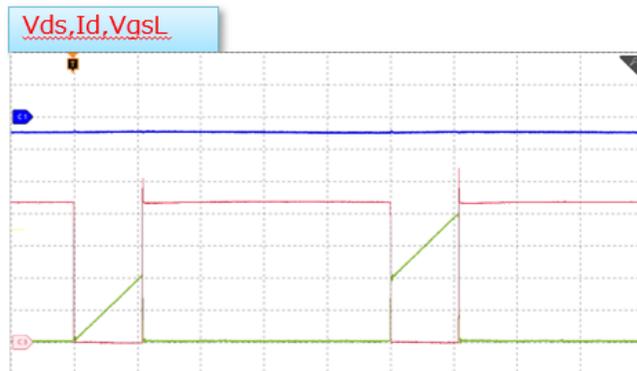
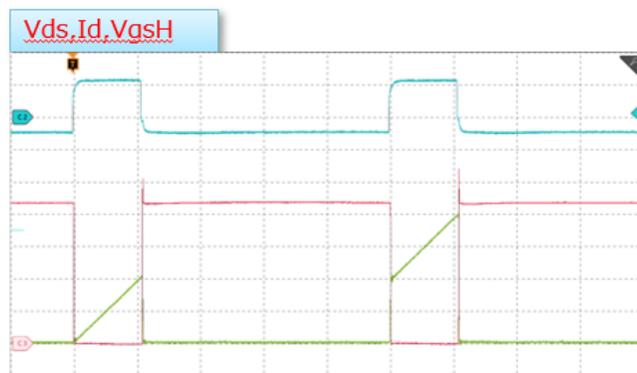
(Data is from Mitsubishi Electric FMF800DC-66BEW)

### 2 pulse test of upper arm

VCC=2200V, Ron:1.5Ω, Roff:1.5Ω, Tj=150°C

VgsL:15V/div, VgsH:15V/div, Vds:500V/div, Id:400A/div, t:20us/div

【2 pulse test】



2LH

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 06 Matching data (2-pulse / Short circuit)

(Data is from Mitsubishi Electric FMF800DC-66BEW)

### 2 pulse test of upper arm (expansion)



VCC=2200V, Ron:1.5Ω, Roff:1.5Ω, Tj=150°C

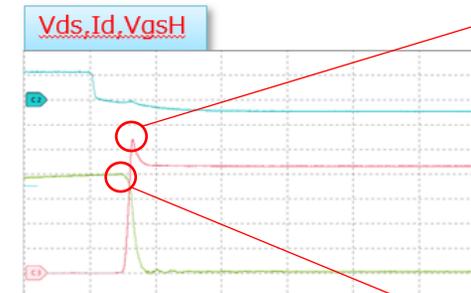
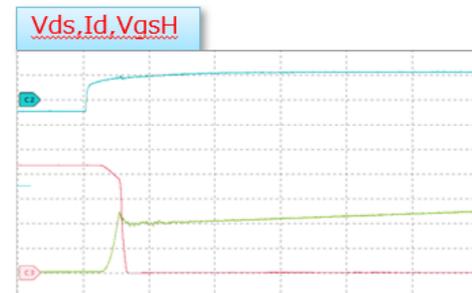
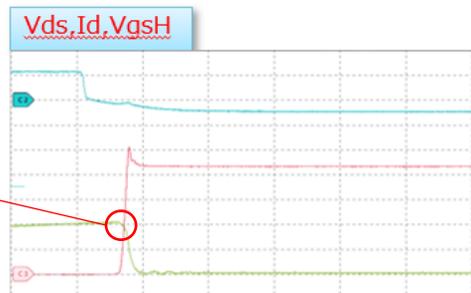
VgsL:15V/div, VgsH:15V/div, Vds:500V/div, Id:400A/div, t:1us/div

Turn OFF / Id =800A

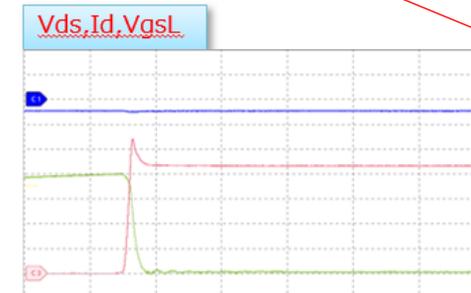
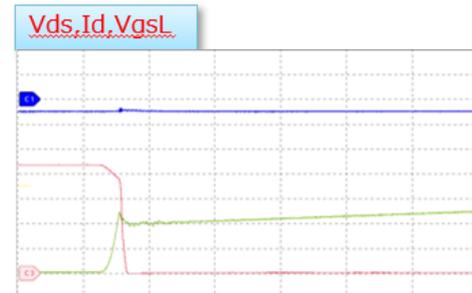
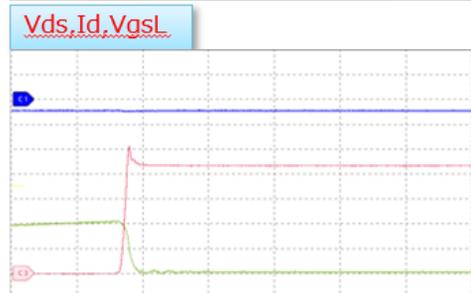
Turn ON / Id =800A

Turn OFF / Id =1600A

Id  
800A



Vds = 2704V



Id  
1600A

Item	Measurement Value	unit
Vdsp	2545	V
dV/dt	23.5	kV/us
dI/dt	7.6	kA/us
Eoff	153	mJ

Item	Measurement Value	unit
dV/dt	27.1	kV/us
dI/dt	5.8	kA/us
Eon	259	mJ

Item	Measurement Value	unit
Vdsp	2704	V
dV/dt	25.6	kV/us
dI/dt	12.5	kA/us
Eoff	380	mJ

# Gate Driver optimized for Mitsubishi Electric 3300V Full SiC power module

## 06 Matching data (2-pulse / Short circuit)

(Data is from Mitsubishi Electric FMF800DC-66BEW)

Short circuit test of upper arm



Currently being measured.  
Please wait until **the end of Oct.**

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CORPORATE GOVERNANCE REPORT



Tamura's mascot "Quenu"



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